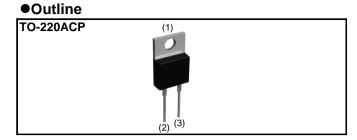
SCS304AH

SiC Schottky Barrier Diode

Datasheet

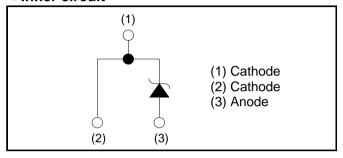
V_R	650V
I _F	4A
Q_{C}	11nC



Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible
- 4) High surge current capability

•Inner circuit



Packaging specifications

	Packaging	Tube
	Reel size (mm)	-
Type	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	50
	Packing code	C9
	Marking	SCS304AH

Construction

Silicon carbide epitaxial planar type

● Absolute maximum ratings (T_i = 25°C)

Parameter		Symbol	Value	Unit
Reverse voltage (repetitive peak)		V_{RM}	650	V
Reverse voltage (DC)		V_R	650	V
Continuous forward	d current (T _c = 140°C)	I _F	4	Α
PW=10ms sinusoidal, T _j =25°C			27	Α
Surge non- repetitive forward current	PW=10ms sinusoidal, T _j =150°C	I_{FSM}	22	А
	PW=10μs square, T _j =25°C		100	А
Repetitive peak forward current		I _{FRM}	20 *1	А
1≦PW≦10ms, T _j =25°C		ر رو ر	3.6	A ² s
i ² t value	1≦PW≦10ms, T _j =150°C	$\int i^2 dt$	2.4	A^2s
Total power disspation		P_{D}	34 *2	W
Junction temperature		T _j	175	°C
Range of storage temperature		T _{stg}	-55 to +175	°C

^{*1} T_c=100°C, T_i=150°C, Duty cycle=10% *2 T_c=25°C

●Electrical characteristics (T_i = 25°C)

Parameter	Symbol	Conditions	Values			l lm:t
			Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =20μA	650	-	-	V
	V _F	I _F =4A,T _j =25°C	-	1.35	1.50	V
Forward voltage		I _F =4A,T _j =150°C	-	1.44	1.71	V
		I _F =4A,T _j =175°C	-	1.50	-	V
Reverse current	I _R	V _R =650V,T _j =25°C	-	0.012	20.0	μΑ
		V _R =650V,T _j =150°C	-	0.8	80	μΑ
		V _R =650V,T _j =175°C	-	2.4	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	200	-	pF
		V _R =650V,f=1MHz	-	18	-	pF
Total capacitive charge	Q _C	V _R =400V,di/dt=350A/μs	-	11	-	nC
Switching time	t _C	V _R =400V,di/dt=350A/μs	-	14	-	ns
Non-repetetive Avaranche Energy	E _{ava}	L=1mH	-	48	-	mJ

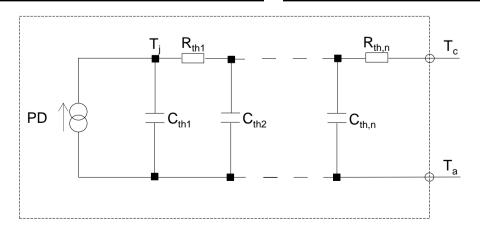
Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Offic
Thermal resistance	R _{th(j-c)}	-	-	3.0	4.4	K/W

●Typical Transient Thermal Characteristics

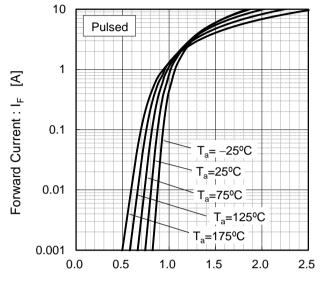
Symbol	Value	Unit
R _{th1}	3.91×10 ⁻²	
R _{th2}	3.76×10 ⁻¹	K/W
R _{th3}	2.54×10 °	

Symbol	Value	Unit
C _{th1}	1.01×10 ⁻⁴	
C _{th2}	4.02×10 ⁻⁴	Ws/K
C _{th3}	1.19×10 ⁻³	



•Electrical characteristic curves

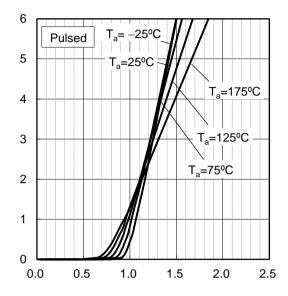
Fig.1 V_F - I_F Characteristics



Forward Voltage : V_F [V]

Fig.2 V_F - I_F Characteristics

Forward Current : IF [A]



Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics

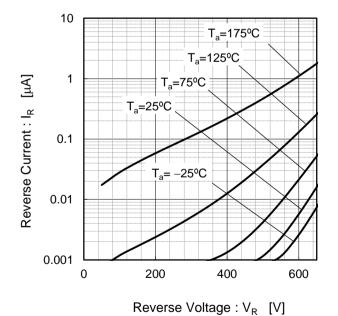
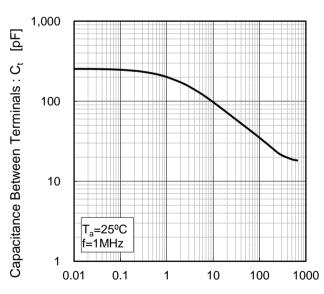


Fig.4 V_R-C_t Characteristics



Reverse Voltage : V_R [V]

Electrical characteristic curves

Fig.5 Typical Transient Thermal Resistance vs. Pulse Width 10 Transient Thermal Resistance: Z_{thJC} [K/W] T₀=25°C Single Pulse 0.1 0.01 0.000001 0.001 Pulse Width: Pw [s]

Fig.6 Power Dissipation 40 35 30 25 20 15 10 5 175 25 50 75 100 125 150

Case Temperature : T_c [°C]

Fig.7*3 Maximum peak forward current derating curve I_P - T_c 50 Peak Forward Current: Ip [A] 40 Duty=0.1 30 Duty=0.2 20 Duty=0.5 10 Duty=0.8 D.C. 0 100 25 50 75 125 150 175 Case Temperature : T_c [°C]

*3 Based on max Vf, max R_{th(i-c)} Valid for switching of above 10kHz,

excluding D.C. curve.

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derating curve I_P - T_c (Not guaranteed) 50 Duty=0.1 40 Duty=0.2 30 Duty=0.5 20 10 Duty=0.8 D.C. 0 25 50 75 100 125 150 175 Case Temperature : T_c [°C]

Fig.8*4 Typical peak forward current

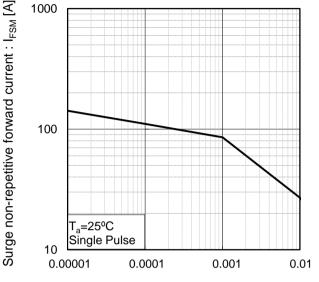
*4 Based on typ Vf, typ R_{th(j-c)} Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

Peak Forward Current : Ip [A]

Power Dissipation [W]

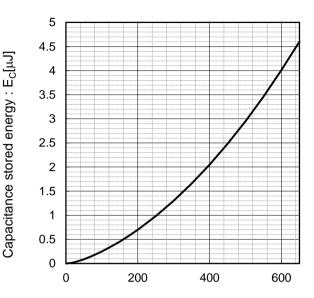
•Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)



Pulse Width: Pw [s]

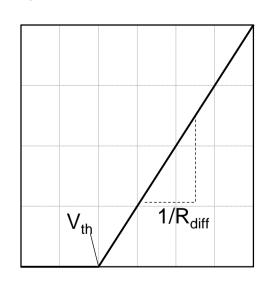
Fig.10 Typical capacitance store energy



Reverse Voltage: V_R [V]

Symplified forward characteristic model

Fig.11 Equivalent forward current curve



Forward Voltage: V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$V_{th} (T_j) = a_0 + a_1 T_j$$

 $R_{diff} (T_j) = b_0 + b_1 T_j + b_2 T_j^2$

Symbol	Typical Value	Unit
a_0	9.66×10 ⁻¹	V
a ₁	-1.1×10 ⁻³	V/°C
b ₀	8.80×10 ⁻²	Ω
b ₁	1.87×10 ⁻⁴	Ω/°C
b ₂	1.92×10 ⁻⁶	Ω/°C ²

 T_i in °C; -55 °C < T_i < 175°C; I_F < 8 A

Forward Current: IF

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